SQM30010EL

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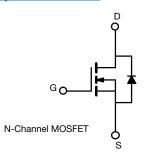
Automotive N-Channel 30 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY						
V _{DS} (V)	30					
$R_{DS(on)}$ (Ω) at V_{GS} = 10 V	0.00135					
$R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 V$	0.00175					
I _D (A)	120					
Configuration	Single					
Package	TO-263					

FEATURES

- TrenchFET® power MOSFET
- · Package with low thermal resistance
- 100 % R_q and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER		SYMBOL	LIMIT	UNIT		
Drain-source voltage		V _{DS}	30	V		
Gate-source voltage		V _{GS}	± 20	v		
Continuous drain current ^a	T _C = 25 °C	- I _D	120			
Continuous drain current "	T _C = 125 °C		120			
Continuous source current (diode conduction) ^a		I _S	120	А		
Pulsed drain current ^b	I _{DM}	360				
Single pulse avalanche current	L = 0.1 mH	I _{AS}	72			
Single pulse avalanche energy	L = 0.1 mm	E _{AS}	259	mJ		
Maximum power dissignation ^b	T _C = 25 °C	PD	375	W		
	T _C = 125 °C	, D	125	vv		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C		

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-ambient	PCB mount ^c	R _{thJA}	40	°C/W		
Junction-to-case (drain)		R _{thJC}	0.4	0/10		

Notes

- a. Package limited
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- c. When mounted on 1" square PCB (FR4 material)

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = 250 \mu\text{A}$		30	-	-	v
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$		1.5	2.0	2.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, $V_{GS} = \pm 20 V$	-	-	± 100	nA
	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 30 V		-	1	
Zero gate voltage drain current		$V_{GS} = 0 V$	$V_{DS} = 30 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	50	μA
		$V_{GS} = 0 V$	$V_{DS} = 30 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	800	μA
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	100	-	-	Α
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 40 A	-	0.00110	0.00135	Ω
		V _{GS} = 10 V	I _D = 40 A, T _J = 125 °C	-	-	0.00191	
		$V_{GS} = 10 V$	I _D = 40 A, T _J = 175 °C	-	-	0.00220	
		V _{GS} = 4.5 V	I _D = 35 A	-	0.00143	0.00175	Ω
Forward transconductance b	9 _{fs}	V _{DS}	= 15 V, I _D = 40 A	-	233	-	S
Dynamic ^b					•		
Input capacitance	C _{iss}	V _{GS} = 0 V	V _{DS} = 15 V, f = 1 MHz	-	20 090	28 000	pF
Output capacitance	C _{oss}			-	7000	9500	
Reverse transfer capacitance	C _{rss}			-	540	750	
Total gate charge ^c	Qg			-	295	450	
Gate-source charge ^c	Q _{gs}	V _{GS} = 10 V	V _{DS} = 15 V, I _D = 50 A	-	59	-	nC
Gate-drain charge ^c	Q _{gd}			-	59	-	
Gate resistance	Rg	f = 1 MHz		0.5	1.11	1.7	Ω
Turn-on delay time ^c	t _{d(on)}	V_{DD} = 15 V, R _L = 0.2 Ω I _D \cong 50 A, V _{GEN} = 10 V, R _g = 1 Ω		-	30	45	
Rise time ^c	tr			-	240	360	
Turn-off delay time ^c	t _{d(off)}			-	98	150	ns
Fall time ^c	t _f			-	44	70	
Source-Drain Diode Ratings and Chara	cteristics b						
Pulsed current ^a	I _{SM}			-	-	360	А
Forward voltage	V _{SD}	I _F = 60 A, V _{GS} = 0 V		-	0.8	1.5	V
Body diode reverse recovery time	t _{rr}	I _F = 35 A, di/dt = 100 A/μs		-	96	195	ns
Body diode reverse recovery charge	Q _{rr}			-	185	370	nC
Reverse recovery fall time	ta			-	48	-	
Reverse recovery rise time	t _b			-	48	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	-3.4	_	Α

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

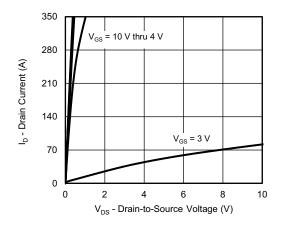
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

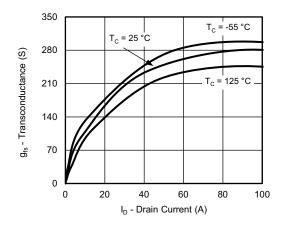
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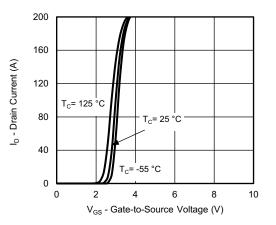
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



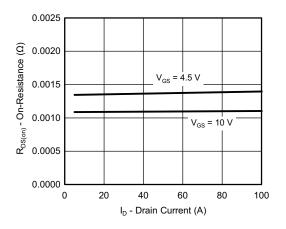
Output Characteristics



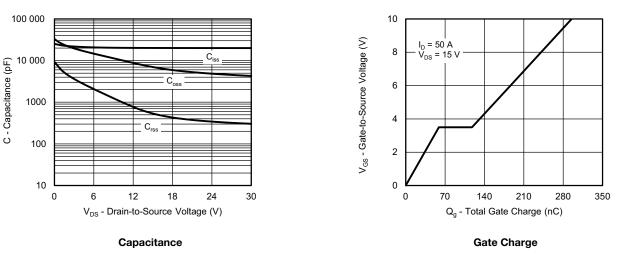
Transconductance



Transfer Characteristics



On-Resistance vs. Drain Current



S18-0667-Rev. A, 02-Jul-2018

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Document Number: 76633

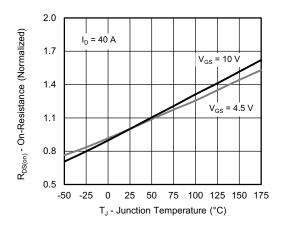
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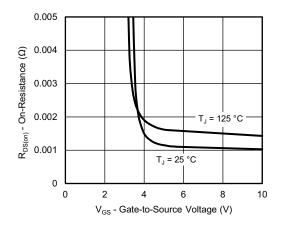
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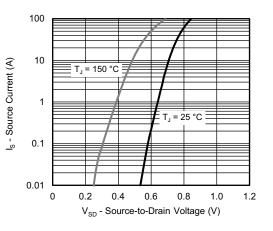
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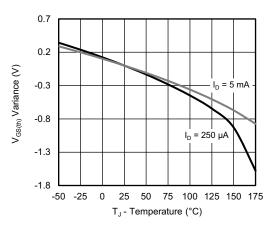
On-Resistance vs. Junction Temperature

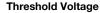


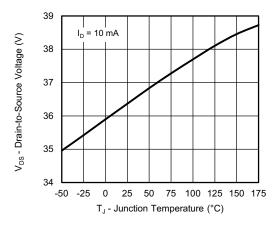
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage







Drain Source Breakdown vs. Junction Temperature

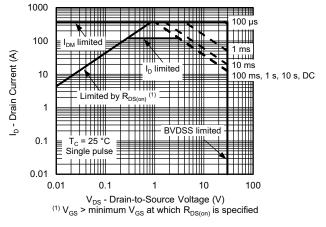
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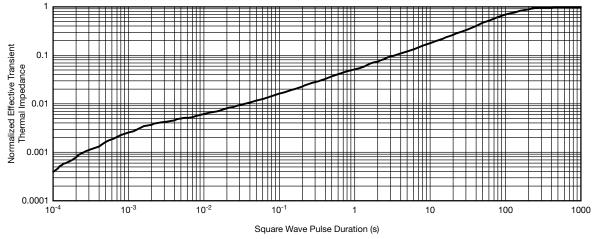
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



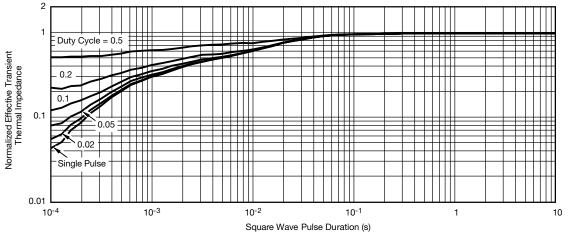




Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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TO-263 (D²PAK): 3-LEAD









DETAIL A (ROTATED 90°)



		INC	HES	MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
A		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
с*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
D2		0.038	0.042	0.965	1.067	
D3		0.045	0.055	1.143	1.397	
D4		0.044	0.052	1.118	1.321	
	E	0.380	0.410	9.652	10.414	
E1		0.245	-	6.223	-	
E2		0.355	0.375	9.017	9.525	
E3		0.072	0.078	1.829	1.981	
	е	0.100 BSC 2.54 BSC		0.100 BSC 2.54 BSC		
	К	0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
	L4	0.010 BSC		0.254 BSC		
	М	-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13 DWG: 5843						

Notes

- 1. Plane B includes maximum features of heat sink tab and plastic. 2. No more than 25 % of L1 can fall above seating plane by
- max. 8 mils.3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB.
 - Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

This feature is for thick lead.

Revison: 30-Sep-13



RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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